TF21038U

Half-Bridge Gate Driver
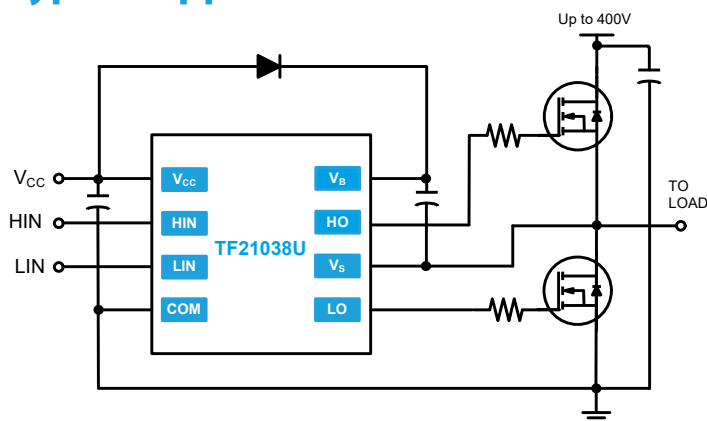
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Features

- **Floating high-side driver in bootstrap operation to 400V**
- **Drives two N-channel MOSFETs or IGBTs in a half bridge configuration**
- **Designed for enhanced performance in noisy motor applications**
- **210mA source/360mA sink output current capability**
- **Outputs tolerant to negative transients**
- **Internal dead time of 420ns to protect MOSFETs**
- **Wide low side gate driver supply voltage: 10V to 20V**
- **Logic input (HIN and LIN) 3.3V capability**
- **Schmitt triggered logic inputs**
- **Undervoltage lockout for V_{cc} (logic and low side supply)**
- **Extended temperature range: -40°C to +125°C**

Description

The TF21038U is a high voltage, high speed gate driver capable of driving N-channel MOSFETs and IGBTs in a half bridge configuration. TF Semiconductors's high voltage process enables the TF21038U high side to switch to 400 V in a bootstrap operation.

The TF21038U logic inputs are compatible with standard TTL and CMOS levels (down to 3.3V) to interface easily with controlling devices. The driver outputs feature high pulse current buffers designed for minimum driver cross conduction. TF21038U has a fixed internal deadtime of 420ns (typical).

The TF21038U is offered in a SOIC-8(N) package and operates over an extended -40 °C to +125 °C temperature range.
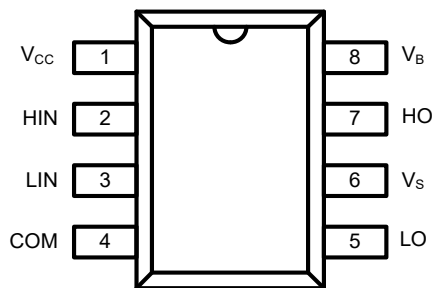
Applications

- Motor Controls
- DC-DC Converters
- AC-DC Inverters
- Motor Drives

SOIC-8(N)

Typical Application

Up to 400V

V_{CC}
HIN
LIN

V_{CC}	V_B
HIN	HO
LIN	V_S
COM	LO

TF21038U

TO LOAD

Ordering Information

Year Year Week Week

PART NUMBER	PACKAGE	PACK / Qty	MARK
TF21038U-TAU	SOIC-8(N)	Tube / 100	YYWW TF21038U Lot ID
TF21038U-TAH	SOIC-8(N)	T&R / 2500	

Pin Diagrams

Top View: SOIC-8

TF21038U

Pin Descriptions

PIN NAME	PIN NUMBER	PIN DESCRIPTION
V_{CC}	1	Logic and low side supply
HIN	2	Logic input for high-side gate driver output in phase with HO
LIN	3	Logic input for low-side gate driver output in phase with LO
COM	4	Low-side and logic return
LO	5	Low-side gate drive output
V_S	6	High-side floating supply return
HO	7	High-side gate drive output
V_B	8	High-side floating supply

Functional Block Diagram
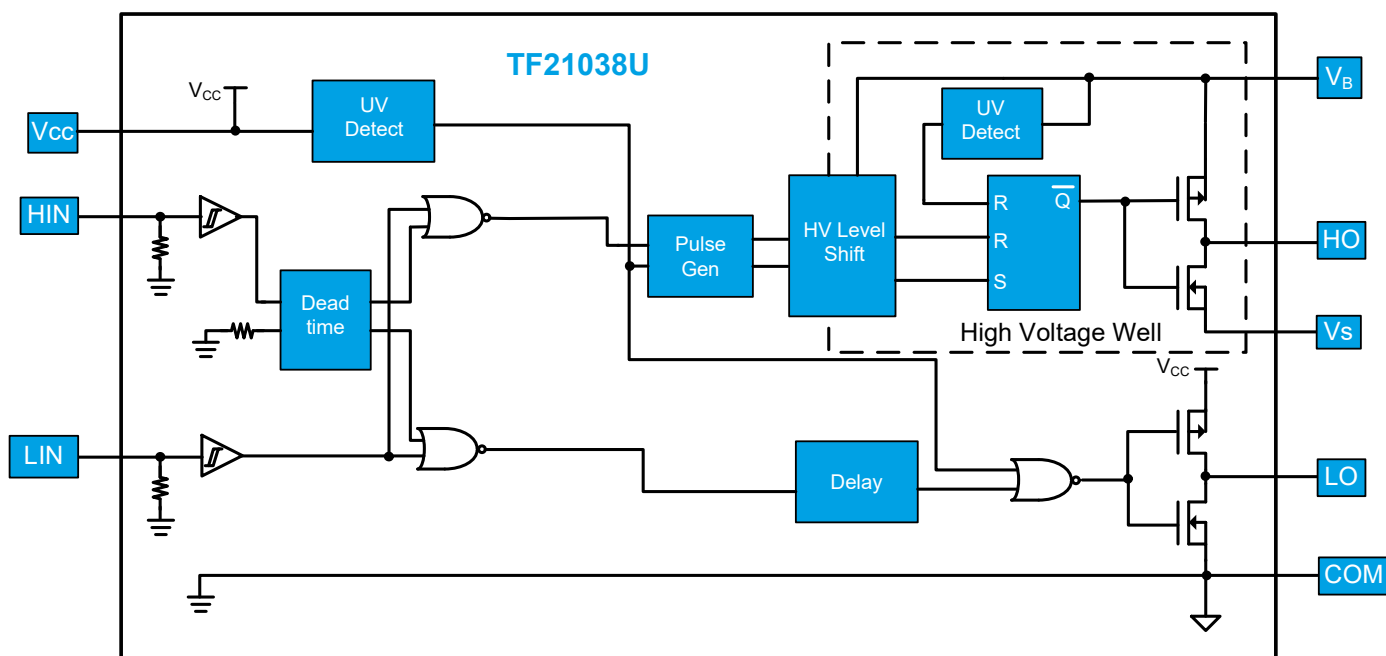
Absolute Maximum Ratings *(NOTE1)*

V_B - High side floating supply voltage......................-0.3V to +420V
V_S - High side floating supply offset voltage....V_B-24V to V_B+0.3V
V_{HO}-High side floating output voltage...................V_S-0.3V to V_B+0.3V
dV_S/dt - Offset supply voltage transient..................................50 V/ns

V_{CC} - Low-side fixed supply voltage..............................-0.3V to +24V
V_{LO} - Low-side output voltage....................................-0.3V to V_{CC}+0.3V
V_{IN} - Logic input voltage (HIN and LIN)..................-0.3V to V_{CC} +0.3V

NOTE1 *Stresses beyond those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.*

P_D - Package power dissipation at $T_A \le 25$ °C
    SOIC-8...0.625W

SOIC-8(N) Thermal Resistance *(NOTE2)*
    θ_{JA}...200 °C/W

T_J - Junction operating temperature......................................+150 °C
T_L - Lead Temperature (soldering, 10 seconds)......................+300 °C
T_{stg} - Storage temerature ....-55 to 150 °C

NOTE2 *When mounted on a standard JEDEC 2-layer FR-4 board.*

Recommended Operating Conditions

Symbol	Parameter	MIN	MAX	Unit
V_B	High side floating supply absolute voltage	V_S + 10	V_S + 20	V
V_S	High side floating supply offset voltage	*NOTE3*	400	V
V_{HO}	High side floating output voltage	V_S	V_B	V
V_{CC}	Low side fixed supply voltage	10	20	V
V_{LO}	Low side output voltage	0	V_{CC}	V
V_{IN}	Logic input voltage (HIN and LIN)	0	5	V
T_A	Ambient temperature	-40	125	°C

NOTE3 *Logic operational for VS of -5V to +400V.*

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DC Electrical Characteristics *(NOTE4)*

V_{BIAS} (V_{CC}, V_{BS}) = 15V, T_A = 25 °C , unless otherwise specified.

Symbol	Parameter	Conditions	MIN	TYP	MAX	Unit
V_{IH}	Logic "1" input voltage	V_{CC} = 10V to 20V *NOTE5*	2.5			V
V_{IL}	Logic "0" input voltage				0.8	
V_{OH}	High level output voltage, V_{BIAS} - V_O	I_O = 2mA		0.05	0.2	
V_{OL}	Low level output voltage, V_O	I_O = 2mA		0.02	0.1	
I_{LK}	Offset supply leakage current	VB = VS = 400V			50	µA
I_{BSQ}	Quiescent V_{BS} supply current	V_{IN} = 0V or 5V		7		
I_{CCQ}	Quiescent V_{CC} supply current	V_{IN} = 0V or 5V		350	500	
I_{IN+}	Logic "1" input bias current	VIN = 5V		3	10	
I_{IN-}	Logic "0" input bias current	VIN = 0V			5	
V_{CCUV+}	V_{CC} supply under-voltage positive going threshold		8.0	8.9	9.8	V
V_{CCUV-}	V_{CC} supply under-voltage negative going threshold		7.4	8.2	9.0	
V_{BSUV+}	V_{BS} supply under-voltage positive going threshold			6.3		V
V_{BSUV-}	V_{BS} supply under-voltage negative going threshold			5.2		V
I_{O+}	Output high short circuit pulsed current	V_O = 0V, PW ≤ 10 µs	130	210		mA
I_{O-}	Output low short circuit pulsed current	V_O = 15V, PW ≤ 10 µs	230	360		

NOTE4 *The V_{IN}, V_{TH}, and I_{IN} parameters are applicable to the two logic input pins: HIN and LIN. The V_O and I_O parameters are applicable to the respective output pins: HO and LO*

NOTE5 *For optimal operation, it is recommended that the input pulse (to HIN and LIN) should have an amplitude of 2.5V minimum with a pulse width of 800ns minimum.*

AC Electrical Characteristics

V_{BIAS} (V_{CC}, V_{BS}) = 15V, C_L = 1000pF, and T_A = 25 °C , unless otherwise specified.

Symbol	Parameter	Conditions	MIN	TYP	MAX	Unit
t_{on}	Turn-on propagation delay	V_S = 0V		100	220	
t_{off}	Turn-off propagation delay	V_S = 400V		100	220	
t_{DM}	Delay matching, HS & LS turn-on/turn-off				50	
t_r	Turn-on rise time	V_S = 0V		70	150	ns
t_f	Turn-off fall time			35	90	
t_{DT}	Deadtime: $t_{DT\ LO-HO}$ & $t_{DT\ HO-LO}$		300	420	650	

Timing Waveforms
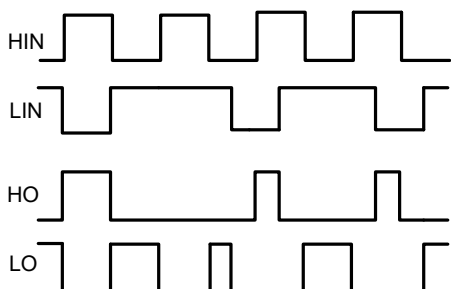
Figure 1. Input / Output Timing Diagram
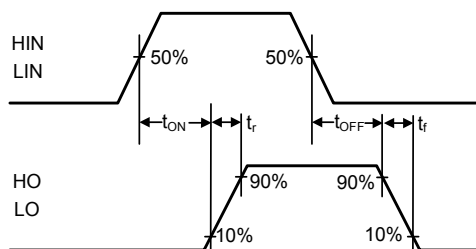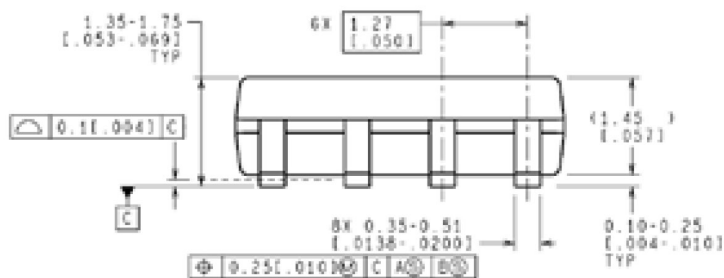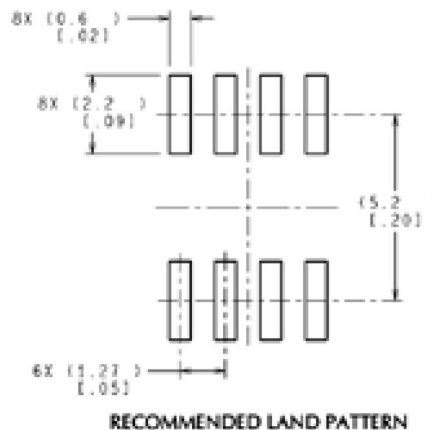

Figure 2. Switching Time Waveform Definitions
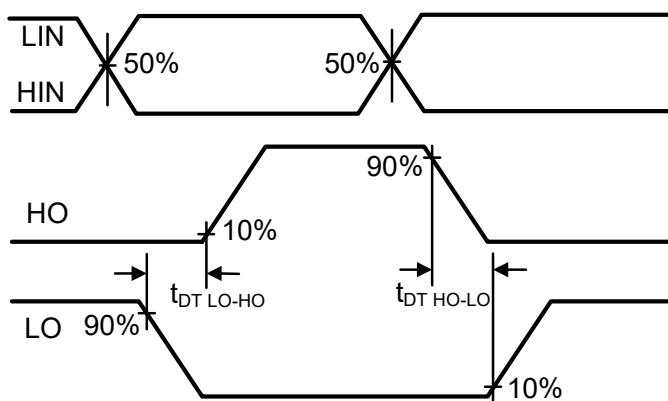
Figure 3. Deadtime Waveform Definitions

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Package Dimensions (SOIC-8 N)

Please contact support@telefunkensemi.com for package availability.

RECOMMENDED LAND PATTERN
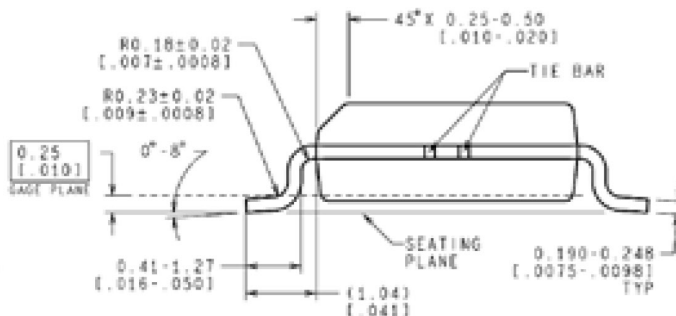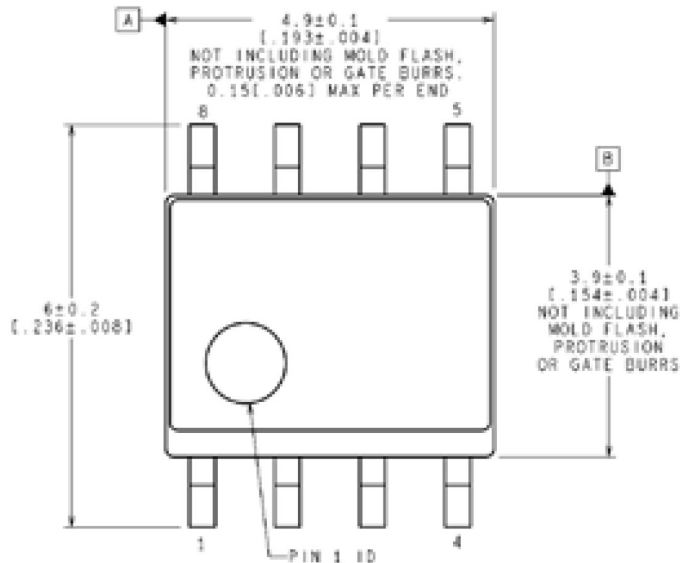
NOTES: UNLESS OTHERWISE SPECIFIED

1. REFERENCE JEDEC REGISTRATION MS-012, VARIATION AA.

CONTROLLING DIMENSION IS MILLIMETER
VALUES IN [ ] ARE INCHES
DIMENSIONS IN [ ] FOR REFERENCE ONLY

Revision History

Rev.	Change	Owner	Date
1.0	First release, AI datasheet	Keith Spaulding	2/5/2019
1.1	Add Note 5	Duke Walton	1/30/2019

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